

# CMS50P04D-HF

P-Channel  
RoHS Device  
Halogen Free



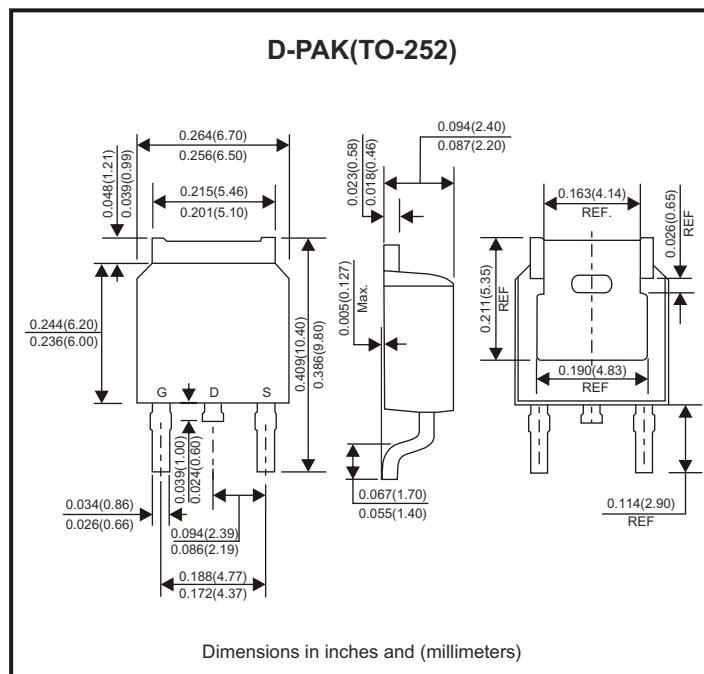
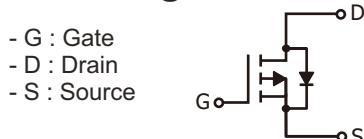
## Features

- Single drive requirement.
- Low On-resistance.
- Fast switching characteristic.

## Mechanical data

- Case: D-PAK/TO-252, molded plastic.

## Circuit Diagram



## Maximum Ratings (at $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Conditions	Symbol	Value	Unit
Drain-source voltage		$V_{DS}$	-40	V
Gate-source voltage		$V_{GS}$	$\pm 20$	V
Continuous drain current	$V_{GS} = -10\text{V}$ , $T_c = 25^\circ\text{C}$ (package limited)	$I_D$	-50	A
	$V_{GS} = -10\text{V}$ , $T_c = 25^\circ\text{C}$ (silicon limited)		-59	
	$V_{GS} = -10\text{V}$ , $T_c = 100^\circ\text{C}$		-37	
	$V_{GS} = -10\text{V}$ , $T_A = 25^\circ\text{C}$		-11	
	$V_{GS} = -10\text{V}$ , $T_A = 100^\circ\text{C}$		-7	
Pulsed drain current	Pulse width limited by safe operating area	$I_{DM}$	-100	A
Power dissipation	$T_c = 25^\circ\text{C}$ (Note 2)	$P_D$	69	W
	$T_c = 100^\circ\text{C}$ (Note 2)		28	
	$T_A = 25^\circ\text{C}$		2.5	
	$T_A = 100^\circ\text{C}$		1.0	
Single pulse avalanche energy	$T_J = 25^\circ\text{C}$ , $V_{DD} = -15\text{V}$ , $L = 1\text{mH}$ , $R_G = 25\Omega$	$E_{AS}$	200	mJ
Single pulse avalanche current		$I_{AS}$	-20	A
Maximum thermal resistance	Junction to case	$R_{\theta JA}$	1.8	°C/W
	Junction to ambient (Note 1)	$R_{\theta JA}$	50	°C/W
Operating junction temperature range		$T_J$	-55 to +150	°C
Storage temperature range		$T_{STG}$	-55 to +150	°C

Notes: 1. The value of  $R_{\theta JA}$  is measured with the device mounted on 1 in<sup>2</sup> FR-4 board with 2 oz. copper, in a still air environment with  $T_A=25^\circ\text{C}$ . The value in any given application depends on the user's specific board design.

2. The power dissipation  $P_D$  is more useful in setting the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

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**Electrical Characteristics** (at  $T_J=25^\circ\text{C}$  unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
<b>Static</b>						
Drain-source breakdown voltage	$\text{BV}_{\text{DSS}}$	$\text{V}_{\text{GS}} = 0\text{V}, \text{I}_D = -250\mu\text{A}$	-40			V
Gate-source threshold voltage	$\text{V}_{\text{GS(th)}}$	$\text{V}_{\text{DS}} = \text{V}_{\text{GS}}, \text{I}_D = -250\mu\text{A}$	-1.0	-1.2	-2.5	
Forward transconductance	$\text{G}_{\text{FS}}$	$\text{V}_{\text{DS}} = -5\text{V}, \text{I}_D = -25\text{A}$		42		S
Gate-source leakage	$\text{I}_{\text{GSS}}$	$\text{V}_{\text{GS}} = \pm 20\text{V}$			$\pm 100$	nA
Zero gate voltage drain current	$\text{I}_{\text{DSS}}$	$\text{V}_{\text{DS}} = -32\text{V}, \text{V}_{\text{GS}} = 0\text{V}$			-1	$\mu\text{A}$
	$\text{I}_{\text{DSS}}$	$\text{V}_{\text{DS}} = -32\text{V}, \text{V}_{\text{GS}} = 0\text{V}, \text{T}_J = 70^\circ\text{C}$			-25	
Drain-source on-state resistance	$* \text{R}_{\text{DS(on)}}$	$\text{I}_D = -25\text{A}, \text{V}_{\text{GS}} = -10\text{V}$		9.7	13	$\text{m}\Omega$
		$\text{I}_D = -15\text{A}, \text{V}_{\text{GS}} = -4.5\text{V}$		12.7	18	
<b>Dynamic</b>						
Total gate charge	$* \text{Q}_g$	$\text{V}_{\text{DS}} = -20\text{V}, \text{I}_D = -25\text{A}, \text{V}_{\text{GS}} = -10\text{V}$		40		$\text{nC}$
Gate-source charge	$* \text{Q}_{\text{gs}}$			13		
Gate-drain charge	$* \text{Q}_{\text{gd}}$			16		
Turn-on delay time	$* \text{t}_{\text{d(on)}}$	$\text{V}_{\text{DS}} = -20\text{V}, \text{V}_{\text{GS}} = -10\text{V}$ $\text{I}_D = -25\text{A}, \text{R}_g = 6\Omega$		24		$\text{nS}$
Turn-on rise time	$* \text{t}_r$			15		
Turn-off delay time	$* \text{t}_{\text{d(off)}}$			120		
Turn-off fall time	$* \text{t}_f$			40		
Input capacitance	$\text{C}_{\text{iss}}$	$\text{V}_{\text{DS}} = -20\text{V}, \text{V}_{\text{GS}} = 0\text{V}, f = 1\text{MHz}$		3987		$\text{pF}$
Output capacitance	$\text{C}_{\text{oss}}$			325		
Reverse transfer capacitance	$\text{C}_{\text{rss}}$			263		
<b>Source-Drain Diode</b>						
Continuous source-drain diode current	$* \text{I}_s$				-50	A
Diode forward voltage	$* \text{V}_{\text{SD}}$	$\text{V}_{\text{GS}} = 0\text{V}, \text{I}_s = -25\text{A}$		-0.9	-1.2	V
Reverse recovery time	$* \text{t}_{\text{rr}}$	$\text{I}_F = -25\text{A}, \text{V}_{\text{GS}} = 0\text{V}$ $d\text{I}_F/dt = 100\text{A}/\mu\text{s}$		36		nS
Reverse recovery charge	$* \text{Q}_{\text{rr}}$			32		nC

\*Pulse test: Pulse width  $\leq 300\mu\text{s}$ , Duty cycle  $\leq 2\%$ .

## Rating and Characteristic Curves (CMS50P04D-HF)

Fig.1 - Typical Output Characteristics

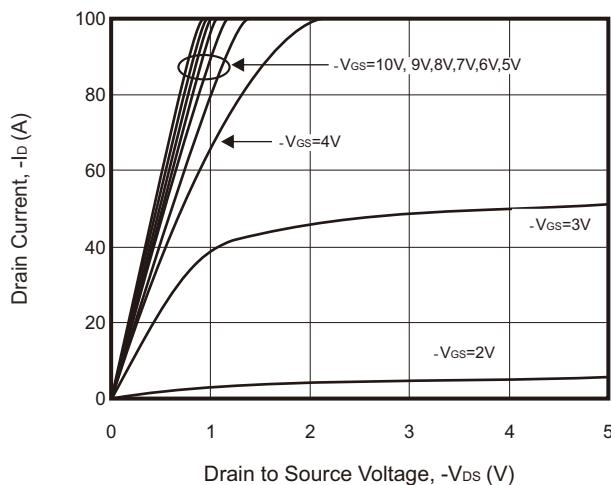


Fig.2 - Static Drain-Source On-State Resistance VS Drain Current

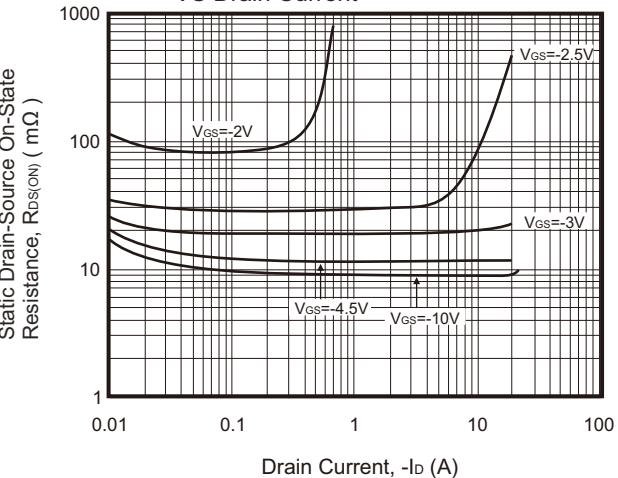


Fig.3 - Static Drain-Source On-State Resistance VS. Gate-Source Voltage

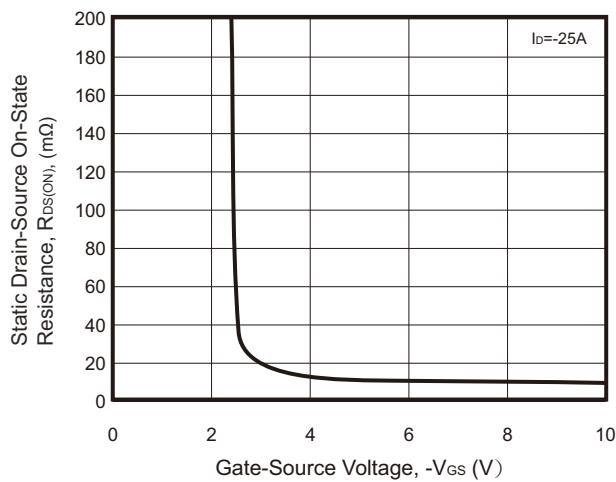


Fig.4 - Capacitance VS Drain-to-Source Voltage

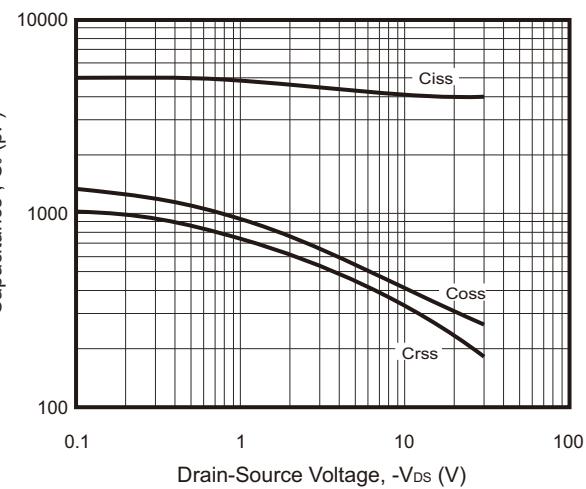


Fig.5 - Forward Transfer Admittance vs Drain Current

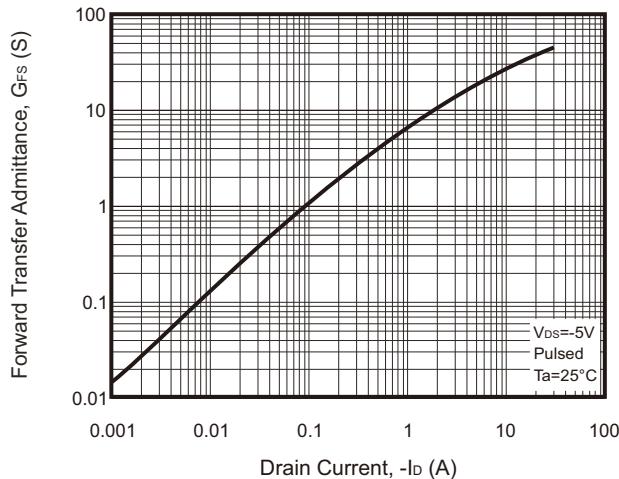
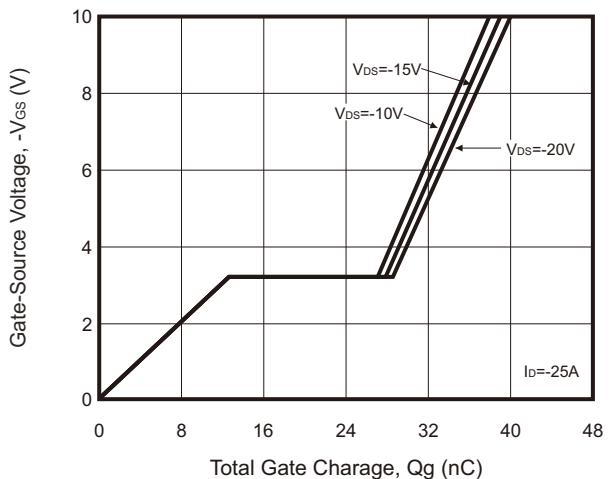


Fig.6 - Gate Charge Characteristics

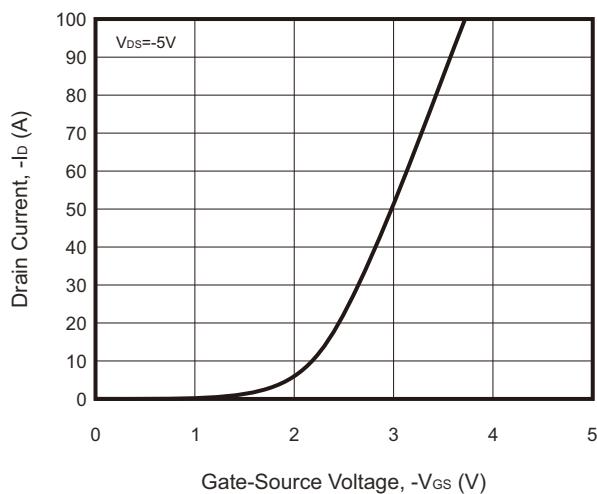


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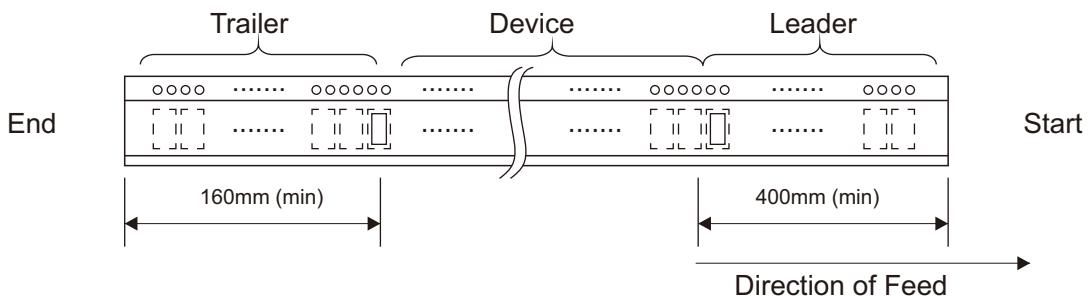
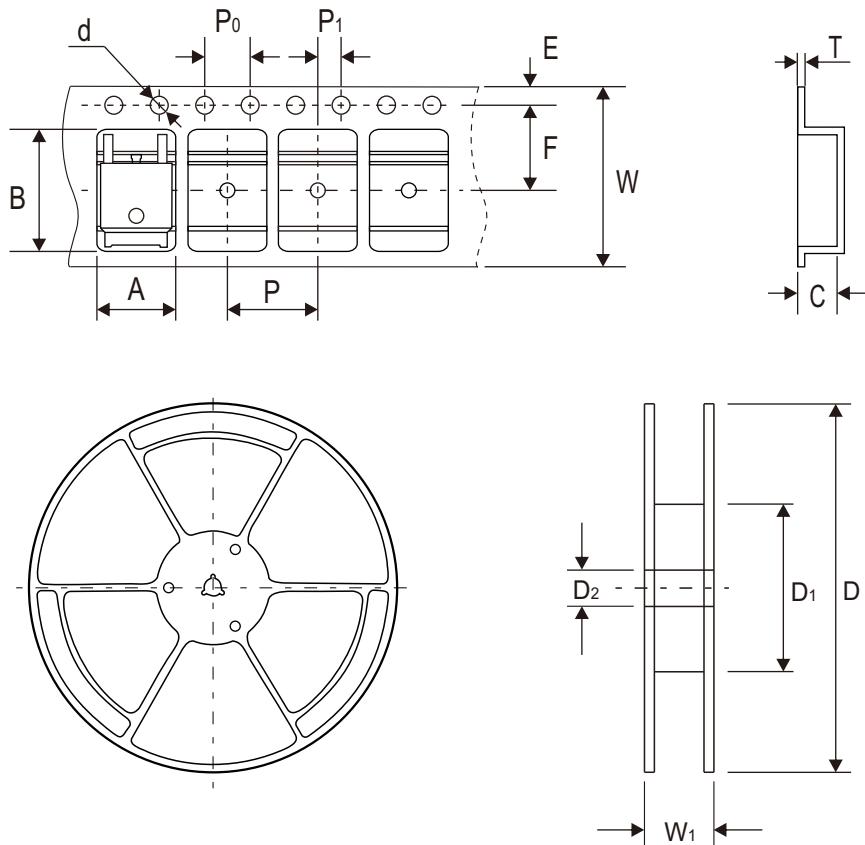
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## Rating and Characteristic Curves (CMS50P04D-HF)

Fig.7 - Typical Transfer Characteristics



## Reel Taping Specification

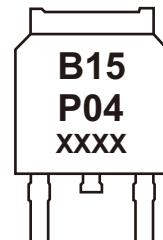


	SYMBOL	A	B	C	d	D	D1	D2
TO-252 (D-PAK)	(mm)	$6.90 \pm 0.10$	$10.50 \pm 0.10$	$2.70 \pm 0.10$	$1.55 \pm 0.05$	$330.00 \pm 2.00$	$100.00 \pm 1.00$	$13.00 \pm 1.00$
	(inch)	$0.272 \pm 0.004$	$0.413 \pm 0.004$	$0.106 \pm 0.004$	$0.061 \pm 0.002$	$12.992 \pm 0.079$	$3.937 \pm 0.039$	$0.512 \pm 0.039$

	SYMBOL	E	F	P	P <sub>0</sub>	P <sub>1</sub>	T	W	W <sub>1</sub>
TO-252 (D-PAK)	(mm)	$1.75 \pm 0.10$	$7.50 \pm 0.10$	$8.00 \pm 0.10$	$4.00 \pm 0.10$	$2.00 \pm 0.10$	$0.30 \pm 0.05$	$16.00 \pm 0.10$	$21.00 \pm 1.00$
	(inch)	$0.069 \pm 0.004$	$0.295 \pm 0.004$	$0.315 \pm 0.004$	$0.157 \pm 0.004$	$0.079 \pm 0.004$	$0.012 \pm 0.002$	$0.630 \pm 0.004$	$0.827 \pm 0.039$

## Marking Code

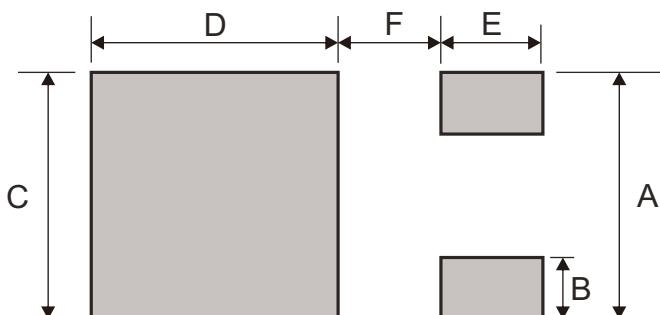
Part Number	Marking Code
CMS50P04D-HF	B15P04



XXXX = Control code

## Suggested P.C.B. PAD Layout

SIZE	TO-252 / DPAK	
	(mm)	(inch)
A	6.17	0.243
B	1.60	0.063
C	5.80	0.228
D	6.20	0.244
E	3.00	0.118
F	2.58	0.101



## Standard Packaging

Case Type	REEL PACK	
	REEL ( pcs )	REEL SIZE (inch)
TO-252/D-PAK	2,500	13